

Features

- 500-mA-Rated Collector Current(single output)
- High-Voltage Outputs:50V
- Output Clamp Diodes

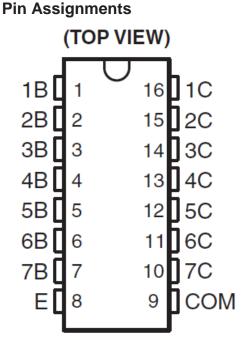
General Description

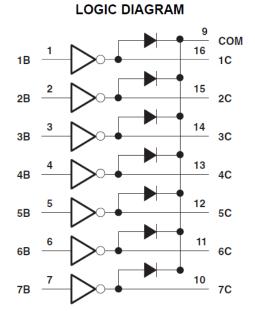
The EC2003 is high-voltage high-current Darlington transistor arrays each containing seven open collector common emitter pairs. Each pair is rated at 500mA. Suppression diodes are included for inductive load driving, the inputs and outputs are pinned in opposition to simplify board layout.

- Inputs Compatible With Various Types of
 Logic
- Relay-Driver Applications

These devices are capable of driving a wide range of loads including solenoids, relays, DC motors, LED displays, filament lamps, thermal print-heads and high-power buffers. The EC2003 is available in both a small outline 16-pin package (DIP16, SOP16, SSOP16 and TSSOP16).

Connection Diagram



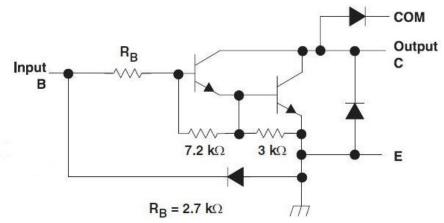




Pin Descriptions

Pin Number	Pin Name	Function
1	1B	Input pair1
2	2B	Input pair1
3	3B	Input pair1
4	4B	Input pair1
5	5B	Input pair1
6	6B	Input pair1
7	7B	Input pair1
8	Е	Common Emitter (ground)
9	СОМ	Common Clamp Diodes
10	7C	Output pair7
11	6C	Output pair6
12	5C	Output pair5
13	4C	Output pair4
14	3C	Output pair3
15	2C	Output pair2
16	1C	Output pair1

Functional Block Diagram



Note: All resistor values shown are nominal.

The collentor-emitter diode is a parasitic structure and should not be used to conduct current. If the collector(s) go below ground an external Schoottky diode should be added to clamp negative undershoots.



Absolute Maximum Ratings ⁽¹⁾

At 25°C free-air temperature (unless otherwise noted)

Symbol	Parameter		Min	Max	Unit
V _{cc}	Collector to emitter voltage			50	V
V _R	Clamp diode reverse voltage(2)			50	V
VI	Input voltage(2)			30	V
I _{CP}	Peak collector current	See typical characteristics		500	mA
Ι _{οκ}	Output clamp current			500	mA
I _{TE}	Total emitter-terminal current			-2.5	А
T _A	Operating free-air temperature range	EC2003	-20	70	°C
θ_{JA}	Thermal Resistance Junction-to-Ambient(3)			63	°C/W
θ_{JC}	Thermal Resistance Junction-to-Case(4)			12	0/11
ТJ	Operating virtual junction temperature			150	°C
T _{STG}	Storage temperature range			150	°C
ESD	Human Body Mo	ode		3000	V

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values are with respect to the emitter/substrate terminal E, unless otherwise noted.
- (3) Maximum power dissipation is a function of TJ(max), θJA, and TA. The maximum allowable power dissipation at any allowable ambient temperature is PD = (TJ(max) – TA)/θJA. Operating at the absolute maximum TJ of 150°C can affect reliability.
- (4) Maximum power dissipation is a function of TJ(max), θJC, and TA. The maximum allowable power dissipation at any allowable ambient temperature is PD = (TJ(max) – TA)/θJC. Operating at the absolute maximum TJ of 150°C can affect reliability.

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Unit
VCC	Collector to Emitter voltage	-	50	V
TA	Operating Ambient Temperature	-40	+105	°C



Parameter		Test	Test Conditions			EC2003A		Unit
		Figure		MIN	TYP	MAX	Unit	
				I _C = 200 mA			2.4	
V I(on)	On-state input voltage	Figure 6	VCE = 2 V	I _C = 250 mA			2.7	V
				IC = 300 mA			3	
			Ij = 250 μA,	I _C = 100 mA		0.9	1.1	
V CE(sat)	Collector-emitter saturation voltage	Figure 5	I ι = 350 μΑ,	IC = 200 mA	-	1	1.3	V
			I ι = 500 μΑ,	IC = 350 mA		1.2	1.6	
		Figure 1	VCE = 50 V,	lı = 0			50	
CEX	Collector cutoff current	Figure 2	V _{CE} = 50 V, T _A = +105°C	lı = 0			100	μA
V F	Clamp forward voltage	Figure 8	IF = 350 mA			1.7	2	V
l I(off)	Off-state input current	Figure 3	V _{CE} = 50 V,	V _{CE} = 50 V, I _C = 500 μA		65		μA
	Input current		V _I = 3.	85 V		0.93	1.35	
li -		Figure 4	VI = 5 V					mA
			VI = 12 V					
		Figure 7					50	
IR	Clamp reverse current	Figure 7	V _R = 50 V	TA = 70°C			100	μA
Ci	Input capacitance		V I = 0, f	= 1 MHz		15	25	pF

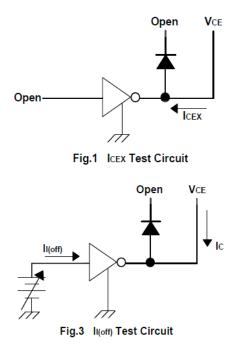
Electrical Characteristics(TA=+25°C, unless otherwise specified)

Switching Characteristics (T_A = +25°C, unless otherwise specified)

	Parameter	Test Conditions	EC2003			UNIT
			MIN	TYP	MAX	
t PLH	Propagation delay time, low- to high-level output	See Figure 9		0.25	1	μs
t PHL	Propagation delay time, high- to low-level output	See Figure 9		0.25	1	μs
V _{OH}	High-level output voltage after switching	V _S = 50 V, I _O = 300 mA, See Figure 9	VS-20			mV



Parameter Measurement Information



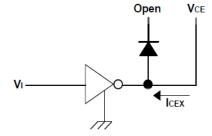


Fig.2 ICEX Test Circuit

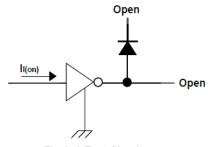


Fig.4 II Test Circuit

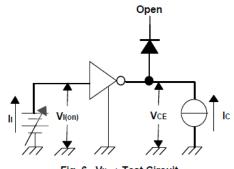


Fig. 6 VI(on) Test Circuit

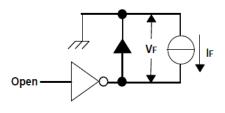


Fig. 8 VF Test Circuit

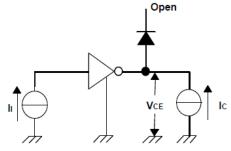
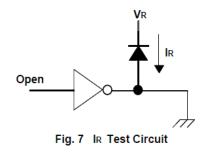


Fig. 5 hFE , VCE(sat) Test Circuit





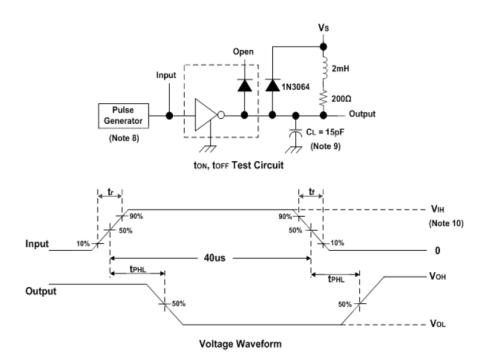


Fig. 9 Latch-Up Test Circuit and Voltage Waveform

Notes: 8. The pulse generator has the following characteristics:

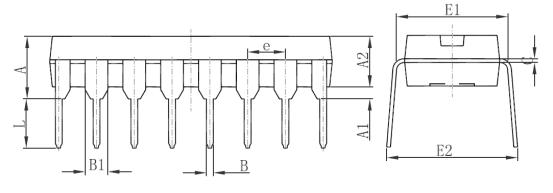
Pulse Width=12.5Hz, output impedance 50Ω, tr≤5ns, tr≤10ns.

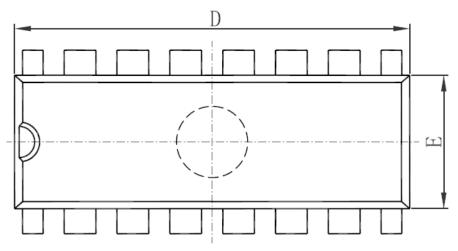
9. C_L includes prove and jig capacitance.

10. V_{IH}=3V



DIP16 Outline Dimensions

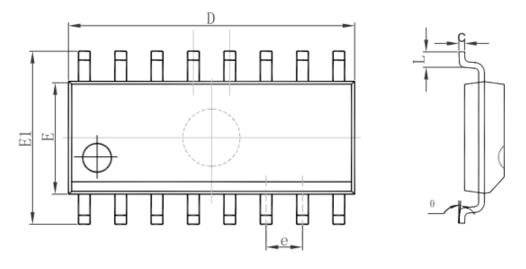


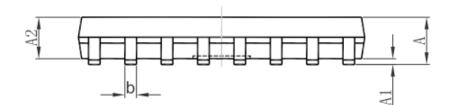


Course a l	Dimensions Ir	n Millimeters	Dimensions	In Inches	
Symbol	Min	Max	Min	Max	
А	3. 710	4. 310	0. 146	0.170	
A1	0. 510		0. 020		
A2	3. 200	3.600	0. 126	0.142	
В	0. 380	0. 570	0.015	0. 022	
B1	1. 524 (BSC)		0. 060 (BSC)		
С	0. 204	0.360	0. 008	0.014	
D	18.800	19. 200	0. 740	0. 756	
E	6. 200	6. 600	0. 244	0. 260	
E1	7.320	7.920	0. 288	0.312	
e	2. 540 (BSC)		0. 100 (BSC)		
L	3.000	3.600	0. 118	0. 142	
E2	8. 400	9.000	0. 331	0. 354	



SOP16 Outline Dimensions

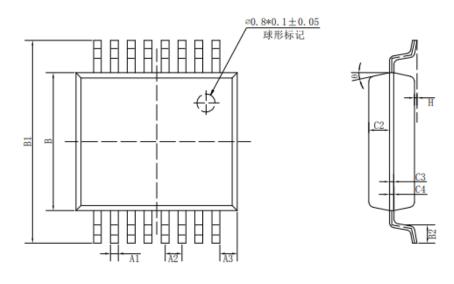


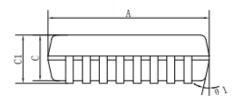


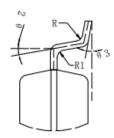
Comb o l	Dimensions Ir	n Millimeters	Dimensions	In Inches
Symbol	Min	Max	Min	Max
Α	1. 350	1. 750	0. 053	0.069
A1	0. 100	0. 250	0. 004	0. 010
A2	1. 350	1. 550	0. 053	0. 061
b	0. 330	0. 510	0. 013	0. 020
С	0. 170	0. 250	0. 007	0. 010
D	9.800	10. 200	0. 386	0. 402
E	3.800	4. 000	0. 150	0. 157
E1	5.800	6. 200	0. 228	0. 244
e	1. 270 (BSC)		0. 050	(BSC)
L	0. 400	1. 270	0. 016	0. 050
θ	0 °	8°	0 °	8°



SSOP16 Outline Dimensions





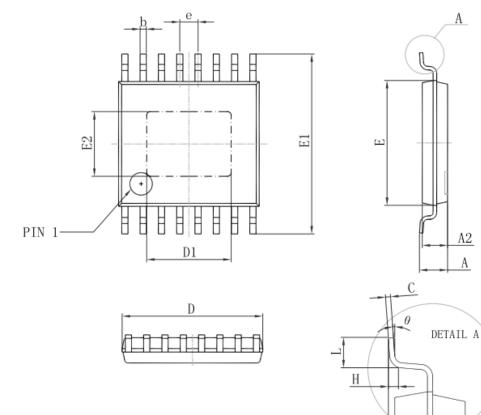


尺寸 标注	最小(mm)	最大(mm)	尺寸 标注	最小(mm)	最大(mm)	
А	6.15	6.25	C3	0.	152	
A1	0.3	0TYP	C4	0.172		
A2	0.6	5TYP	Н	0.05	0.15	
A3	0.6	75TYP	θ	12° TYP4		
В	5.25	5.35	θ1	12° TYP4		
B1	7.65	7.95	θ 2	10° TYP		
B2	0.60	0.80	θ 3	$0^{\circ} \sim 8^{\circ}$		
С	1.70	1.80	R	0. 20TYP		
C1	1.75	1.95	R1	0.15TYP		
C2	C2 0. 799					



A1

TSSOP16 Outline Dimensions



Symbol	Dimensions In	Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
D	4.900	5.100	0.193	0.201	
D1	2.900	3.100	0.114	0.122	
Е	4.300	4.500	0.169	0.177	
b	0.190	0.300	0.007	0.012	
с	0.090	0.200	0.004	0.008	
E1	6.250	6.550	0.246	0.258	
E2	2.200	2.400	0.087	0.094	
Α		1.150		0.043	
A2	0.800	1.000	0.031	0.039	
A1	0.020	0.150	0.001	0.006	
e	0.65 (BSC)	0.026(BSC)		
L	0.500	0.700	0.02	0.028	
Н	0.25(T	0.25(TYP)		TYP)	
θ	1 °	7 °	1°	7 °	